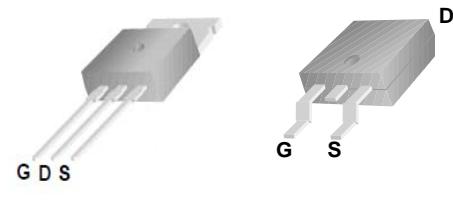
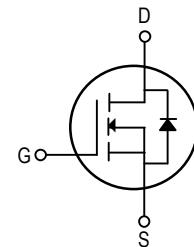


## Features

- 60V/80A  
 $R_{DS(on)}=7.3\text{m}\Omega$  @  $V_{GS}=10\text{V}$
- Lead free and Green Device Available
- Low  $R_{ds-on}$  to Minimize Conductive Loss
- High avalanche Current
- 100% Avalanche Tested



## Application

- Power Supply
- DC-DC Converters
- UPS
- Battery Management System

## Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Maximum	Unit
$V_{DSS}$	Drain-to-Source Voltage	60	V
$V_{GSS}$	Gate-to-Source Voltage	$\pm 25$	V
$I_D^3$	Continuous Drain Current	$T_C=25^\circ\text{C}$	80
		$T_C=100^\circ\text{C}$	66
$I_{DP}^4$	Pulsed Drain Current	$T_C=25^\circ\text{C}$	320
EAS <sup>5</sup>	Avalanche energy	242	mJ
PD	Maximum Power Dissipation	$T_C=25^\circ\text{C}$	125
$T_J, T_{STG}$	Junction & Storage Temperature Range	-55~175	$^\circ\text{C}$

## Thermal Characteristics

Symbol	Parameter	Typical	Unit
$R\theta_{jc}$	Thermal Resistance-Junction to Case	1.0	$^\circ\text{C/W}$
$R\theta_{ja}$	Thermal Resistance-Junction to Ambient	62.5	

**Electrical Characteristics** (TA=25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Typ	Max.	Unit
<b>Static Characteristics</b>						
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	60	—	—	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V	—	—	1	uA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	2	3	4	V
I <sub>GSS</sub>	Gate Leakage Current	V <sub>GS</sub> =±25V, V <sub>DS</sub> =0V	—	—	±100	nA
R <sub>DS(on)</sub> <sup>1</sup>	Drain-Source On-Resistance	V <sub>GS</sub> =10V, I <sub>D</sub> =40A	—	7.3	8	mΩ
<b>Diode Characteristics</b>						
V <sub>SD</sub> <sup>1</sup>	Diode Forward Voltage	I <sub>SD</sub> =40A, V <sub>GS</sub> =0V	—	—	1.3	V
I <sub>s</sub> <sup>3</sup>	Diode Continuous Forward Current	—	—	—	100	A
t <sub>rr</sub>	Reverse Recovery Time	I <sub>S</sub> =40A,	—	70	—	nS
Q <sub>rr</sub>	Reverse Recovery Charge	dI/dt=100A/us	—	100	—	nC
<b>Dynamic Characteristics</b> <sup>2</sup>						
C <sub>iss</sub>	Input Capacitance	V <sub>GS</sub> =0V, V <sub>DS</sub> =25V Frequency=1MHz	—	3970	—	pF
C <sub>oss</sub>	Output Capacitance		—	365	—	
C <sub>rss</sub>	Reverse Transfer Capacitance		—	257	—	
t <sub>d(on)</sub>	Turn-On Delay Time	V <sub>DD</sub> =34V, I <sub>D</sub> =40A, V <sub>GS</sub> =10V,(Note1,4)	—	57	—	nS
t <sub>r</sub>	Rise Time		—	63	—	
t <sub>d(off)</sub>	Turn-Off Delay Time		—	139	—	
t <sub>f</sub>	Fall Time		—	50	—	
<b>Gate Charge Characteristics</b> <sup>2</sup>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DD</sub> =48V, I <sub>D</sub> =40A, V <sub>GS</sub> =10V,(Note1,4)	—	91	—	nC
Q <sub>gs</sub>	Gate-to-Source Charge		—	19	—	
Q <sub>gd</sub>	Gate-to-Drain Charge		—	30	—	

Note: 1: Pulse test; pulse width  $\leq$  300us, duty cycle  $\leq$  2%.

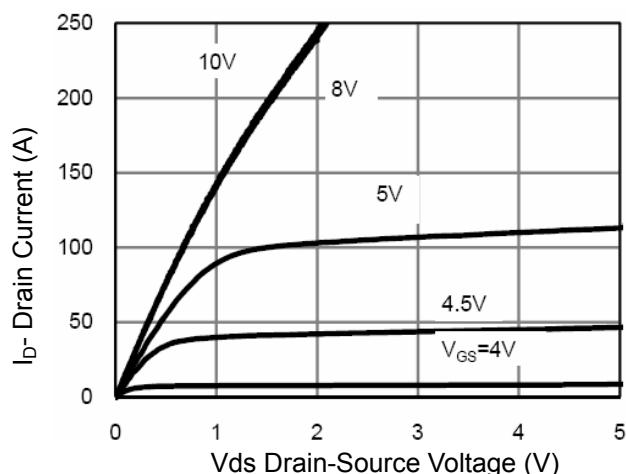
2: Guaranteed by design, not subject to production testing.

3: Package limitation current is 100A.Calculated continuous current based on maximum allowable junction temperature.

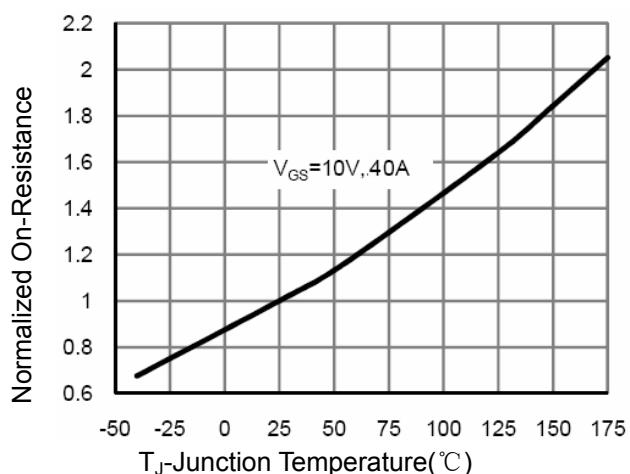
4: Repetitive rating, pulse width limited by max junction temperature.

5: Starting TJ = 25°C,L = 1mH,IAS = 22A.

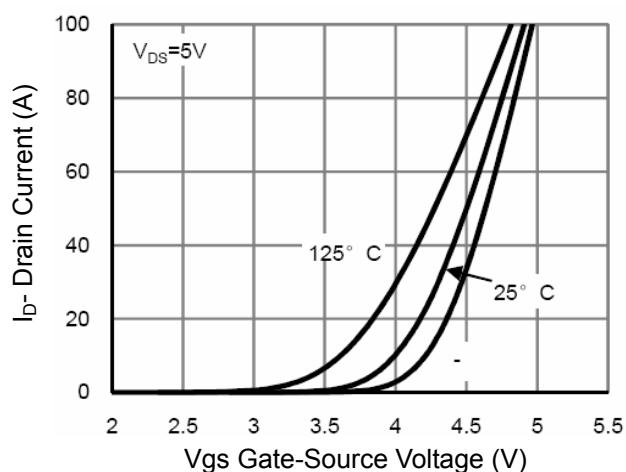
**Typical Operating Characteristics**



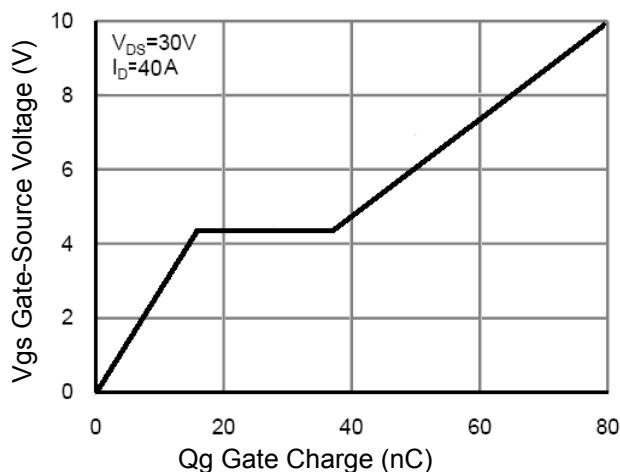
**Figure 1 Output Characteristics**



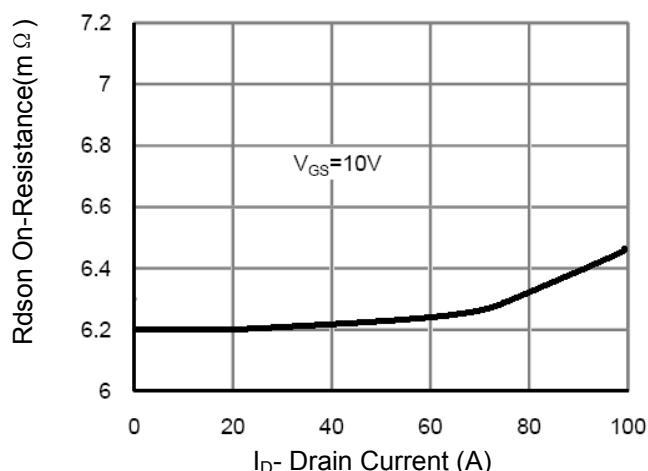
**Figure 4 Rdson-JunctionTemperature**



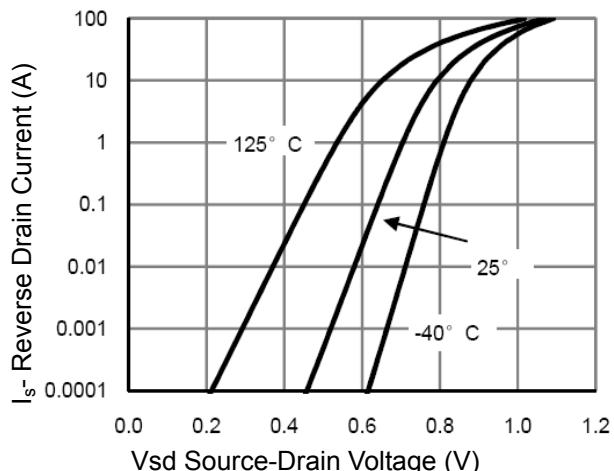
**Figure 2 Transfer Characteristics**



**Figure 5 Gate Charge**



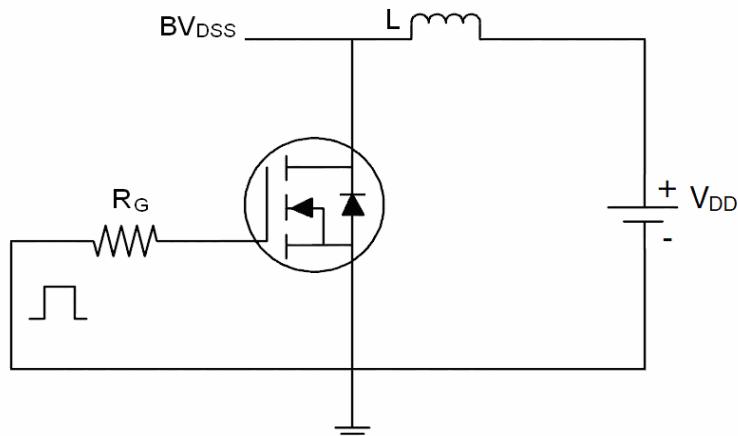
**Figure 3 Rdson- Drain Current**



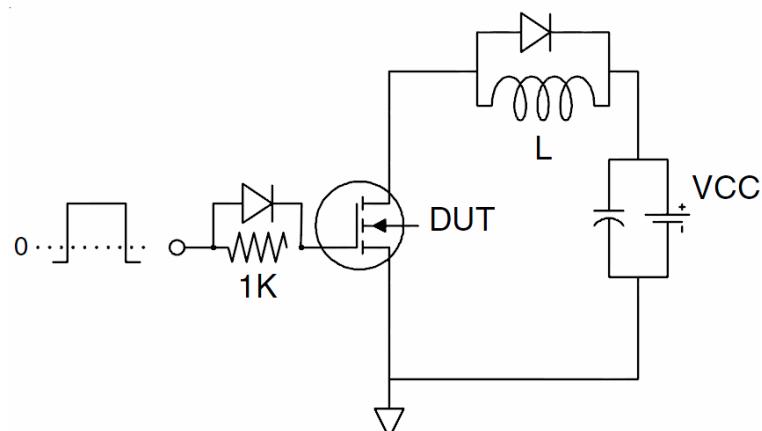
**Figure 6 Source- Drain Diode Forward**

### Test Circuit

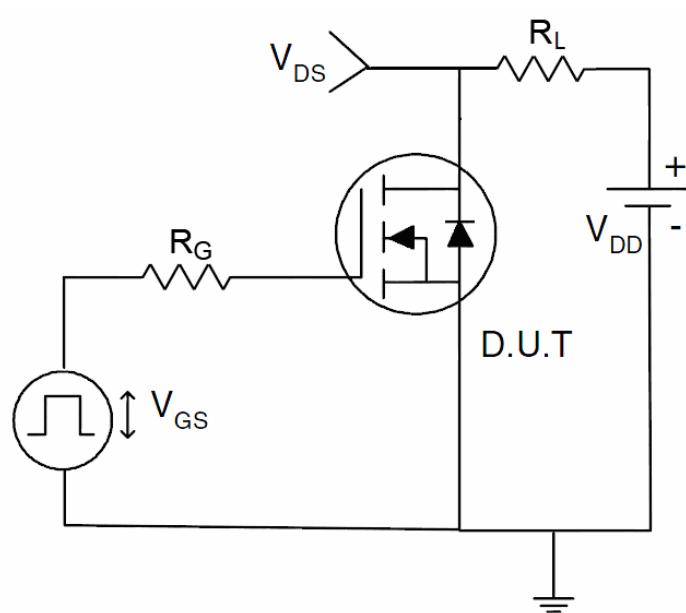
#### 1) $E_{AS}$ test Circuit



#### 2) Gate charge test Circuit



#### 3) Switch Time Test Circuit



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